

**Features**

- Interdigitated amplifying gates
- Fast turn-on and high di/dt
- Low switching losses

**Typical Applications**

- Inductive heating
- Electronic welders
- Self-commutated inverters

$I_{T(AV)}$	<b>3370A</b>
$V_{DRM}/V_{RRM}$	<b>3100 ~ 4000V</b>
$t_q$	<b>50~150<math>\mu</math>s</b>
$I_{TSM}$	<b>35 kA</b>
$I^2t$	<b>6125 10<sup>3</sup>A<sup>2</sup>s</b>

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T <sub>J</sub> (°C)	VALUE			UNIT
					Min	Type	Max	
$I_{T(AV)}$	Mean on-state current	180° half sine wave 50Hz Double side cooled,	$T_C=55^\circ\text{C}$	125			3370	A
$V_{DRM}$ $V_{RRM}$	Repetitive peak off-state voltage Repetitive peak reverse voltage	$t_p=10\text{ms}$		125	3100		4000	V
$I_{DRM}$ $I_{RRM}$	Repetitive peak current	at $V_{DRM}$ at $V_{RRM}$		125			250	mA
$I_{TSM}$	Surge on-state current	10ms half sine wave		125			35	kA
$I^2t$	$I^2t$ for fusing coordination	$V_R=0.6V_{RRM}$						6125
$V_{TO}$	Threshold voltage			125			1.48	V
$r_T$	On-state slope resistance							0.18
$V_{TM}$	Peak on-state voltage	$I_{TM}=2200\text{A}, F=70\text{kN}$		25			3.40	V
dv/dt	Critical rate of rise of off-state voltage	$V_{DM}=0.67V_{DRM}$		125			1000	V/ $\mu$ s
di/dt	Critical rate of rise of on-state current	$V_{DM}=67\%V_{DRM}$ , to4000A Gate pulse $t_r \leq 0.5\mu\text{s}$ $I_{GM}=1.5\text{A}$ Single pulse		125			1200	A/ $\mu$ s
$Q_{rr}$	Recovery charge	$I_{TM}=2000\text{A}, t_p=4000\mu\text{s}$ , $di/dt=-20\text{A}/\mu\text{s}, V_R=100\text{V}$		125		3500		$\mu\text{C}$
$t_q$	Circuit commutated turn-off time	$I_{TM}=2000\text{A}, t_p=4000\mu\text{s}, V_R=100\text{V}$ $dv/dt=30\text{V}/\mu\text{s}, di/dt=-20\text{A}/\mu\text{s}$		125	50		150	$\mu\text{s}$
$I_{GT}$	Gate trigger current	$V_A=12\text{V}, I_A=1\text{A}$		25	50		350	mA
$V_{GT}$	Gate trigger voltage				0.9		3.5	V
$I_H$	Holding current				20		1000	mA
$I_L$	Latching current						1000	mA
$V_{GD}$	Non-trigger gate voltage	$V_{DM}=67\%V_{DRM}$		125			0.3	V
$R_{th(j-c)}$	Thermal resistance Junction to case	D.C. double side cooled					0.007	°C/W
$R_{th(c-h)}$	Thermal resistance case to heat sink	Clamping force 70kN					0.002	
$F_m$	Mounting force				63		84	kN
$T_{vj}$	Junction temperature				-40		125	°C
$T_{stg}$	Stored temperature				-40		140	°C
$W_t$	Weight					1390		g
Outline	P20							

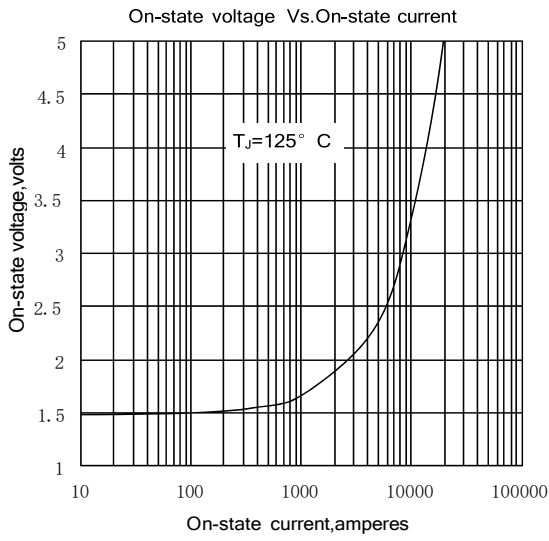


Fig. 1

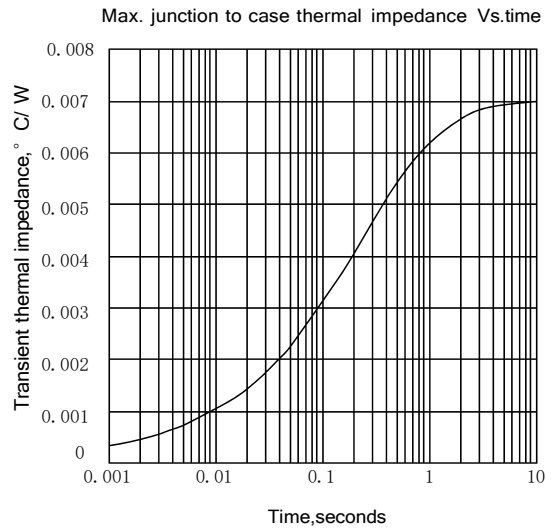


Fig. 2

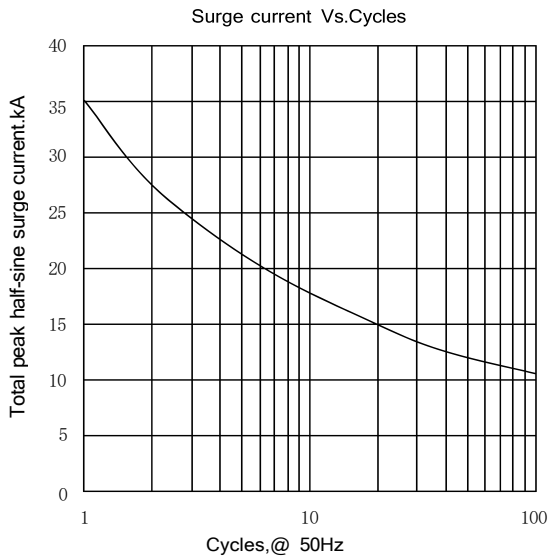


Fig. 3

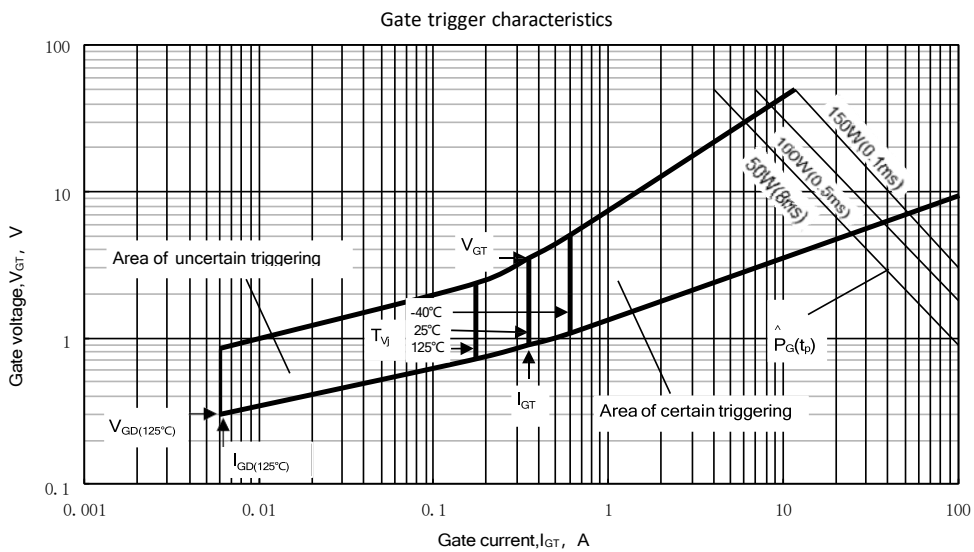
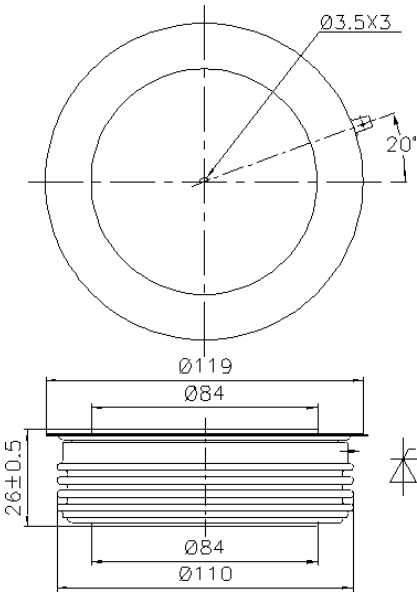


Fig. 4

Outline:



Nlps reserves the right to change specifications without notice.